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DTC114EM~DTC144TM

Digital Transistors (Built-in Resistors)

www.sot23.com.tw

DESCRIPTION

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SOT-723 package which is designed for low power surface mount applications.

The DTC144EM ~ DTC144TM are available in SOT-723 package

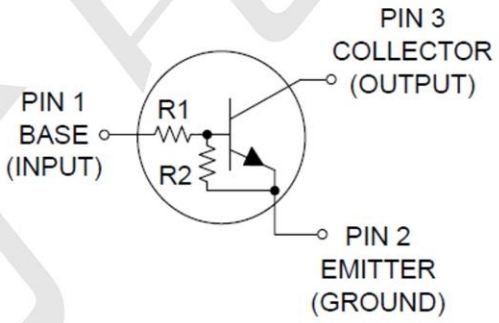
FEATURES

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- The SOT-723 Package can be Soldered using Wave or Reflow.
- Available in 4 mm, 8000 Unit Tape & Reel
- Available in SOT-723 package

ORDERING INFORMATION

Package Type	Part Number
SOT-723	DTC114EM
	DTC124EM
	DTC144EM
	DTC114YM
	DTC114TM
	DTC143TM
	DTC123EM
	DTC143EM
	DTC143ZM
	DTC124XM
	DTC123JM
	DTC115EM
	DTC144WM
	DTC144TM
Note	SPQ: 8,000Pcs/Reel
AiT provides all RoHS Compliant Products	

PIN DESCRIPTION



ABSOLUTE MAXIMUM RATINGS

T_A = 25°C, unless otherwise noted

V_{CBO}, Collector-Base Voltage	50Vdc
V_{CEO}, Collector-Emitter Voltage	50Vdc
I_C, Collector Current	100mAdc

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL CHARACTERISTICS

Parameter	Symbol	Value	Unit
Total Device Dissipation T_A = 25°C Derate above 25°C	P_D	260NOTE1 600NOTE2 2.0NOTE1 4.8 NOTE2	mW mW/°C
Thermal Resistance – Junction-to-Ambient	$R_{\theta JA}$	480NOTE1 205NOTE2	°C/W
Junction Temperature	T_J	150	°C
Storage Temperature Range	T_{STG}	−55 to +150	°C

NOTE1: FR−4 @ Minimum Pad
NOTE2: FR−4 @ 1.0 x 1.0 inch Pad

ELECTRICAL CHARACTERISTICS

T_A = 25°C, unless otherwise noted

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
OFF CHARACTERISTICS							
Collector−Base Cutoff Current	I_{CBO}	V_{CB} = 50V, I_E = 0		-	-	100	nAdc
Collector−Emitter Cutoff Current	I_{CEO}	V_{CE} = 50V, I_B = 0		-	-	500	nAdc
Emitter−Base Cutoff Current	I_{EBO}	V_{EB} = 6.0V, I_C = 0	DTC114EM	-	-	0.5	mAdc
			DTC124EM			0.2	
			DTC144EM			0.1	
			DTC114YM			0.2	
			DTC114TM			0.9	
			DTC143TM			1.9	
			DTC123EM			2.3	
			DTC143EM			1.5	
			DTC143ZM			0.18	
			DTC124XM			0.13	
			DTC123JM			0.2	
			DTC115EM			0.05	
			DTC144WM			0.13	
			DTC144TM			0.2	
Collector−Base Breakdown Voltage	$V_{(BR)CBO}$	I_C = 10μA, I_E = 0		50	-	-	Vdc
Collector−Emitter Breakdown Voltage[NOTE3]	$V_{(BR)CEO}$	I_C = 2.0mA, I_B = 0		50	-	-	Vdc
ON CHARACTERISTICS[NOTE3]							
DC Current Gain	h_{FE}	V_{CE}=10V, I_C=5.0mA	DTC114EM	35	60	-	-
			DTC124EM	60	100		
			DTC144EM	80	140		
			DTC114YM	80	140		
			DTC114TM	160	350		
			DTC143TM	160	350		
			DTC123EM	8.0	15		
			DTC143EM	15	30		
			DTC143ZM	80	200		
			DTC124XM	80	150		
			DTC123JM	80	140		
			DTC115EM	80	150		
			DTC144WM	80	140		
			DTC144TM	160	350		

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Collector−Emitter Saturation Voltage	$V_{CE(sat)}$	I_C = 10mA, I_B = 0.3mA		-	-	0.25	Vdc
		I_C = 10mA, I_B = 5mA	DTC123EM				
		I_C = 10mA, I_B = 1mA	DTC143TM DTC114TM DTC143EM DTC143ZM DTC124XM DTC144TM				
Output Voltage (on)	V_{OL}	V_{CC} = 5.0V, V_B = 2.5V, R_L = 1.0kΩ	DTC114EM DTC124EM DTC114YM DTC114TM DTC143TM DTC123EM DTC143EM DTC143ZM DTC124XM DTC123JM	-	-	0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2	Vdc
		V_{CC} = 5.0V, V_B = 3.5V, R_L = 1.0kΩ	DTC144EM DTC144TM			0.2 0.2	
		V_{CC} = 5.0V, V_B = 5.5V, R_L = 1.0kΩ	DTC115EM			0.2	
		V_{CC} = 5.0V, V_B = 4.0V, R_L = 1.0kΩ	DTC144WM			0.2	
Output Voltage (off)	V_{OH}	V_{CC} = 5.0V, V_B = 0.5V, R_L = 1.0kΩ		4.9	-	-	Vdc
		V_{CC} = 5.0V, V_B = 0.25V, R_L = 1.0kΩ	DTC143TM DTC143ZM DTC114TM DTC144TM				

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
Input Resistor	R1	DTC114EM		7.0	10	13	kΩ
		DTC124EM		15.4	22	28.6	
		DTC144EM		32.9	47	61.1	
		DTC114YM		7.0	10	13	
		DTC114TM		7.0	10	13	
		DTC143TM		3.3	4.7	6.1	
		DTC123EM		1.5	2.2	2.9	
		DTC143EM		3.3	4.7	6.1	
		DTC143ZM		3.3	4.7	6.1	
		DTC124XM		15.4	22	28.6	
		DTC123JM		1.54	2.2	2.86	
		DTC115EM		70	100	130	
		DTC144WM		32.9	47	61.1	
		DTC144TM		32.9	47	61.1	
Resistor Ratio	R_1/R_2	DTC114EM/DTC124EM/ DTC144EM/DTC115EM		0.8	1.0	1.2	
		DTC114YM		0.17	0.21	0.25	
		DTC143TM/DTC114TM/ DTC144TM		–	–	–	
		DTC123EM/DTC143EM		0.8	1.0	1.2	
		DTC143ZM		0.055	0.1	0.185	
		DTC124XM		0.38	0.47	0.56	
		DTC123JM		0.038	0.047	0.056	
		DTC144WM		1.7	2.1	2.6	
Input Voltage	$V_{I(off)}$	V_{CC} = 5.0V, I_O= 100μA	DTC123JM	-	-	0.5	V
Input Voltage	$V_{I(on)}$	V_O = 0.3V, I_O = 5mA	DTC123JM	1.1	-	-	V

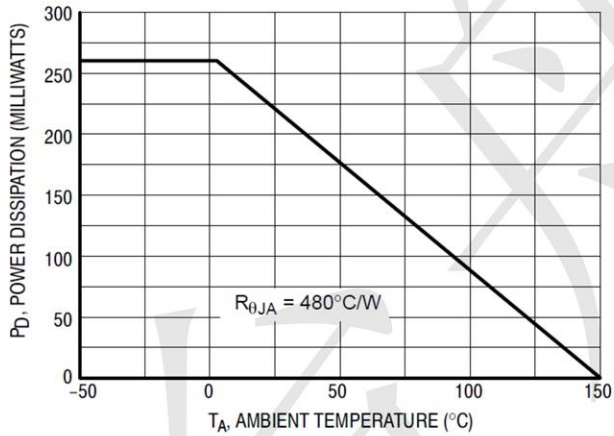
NOTE3: Pulse Test: Pulse Width < 300 μs, Duty Cycle < 2.0%

RESISTOR VALUES

Device	R1 (k)	R2 (k)
DTC114EM	10	10
DTC124EM	22	22
DTC144EM	47	47
DTC114YM	10	47
DTC114TM	10	∞
DTC143TM	4.7	∞
DTC123EM	2.2	2.2
DTC143EM	4.7	4.7
DTC143ZM	4.7	47
DTC124XM	22	47
DTC123JM	2.2	47
DTC115EM	100	100
DTC144WM	47	22
DTC144TM	47	∞

TYPICAL CHARACTERISTICS

Figure 1. Derating Curve



DTC114EM

Figure 2. $V_{CE(sat)}$ vs. I_C

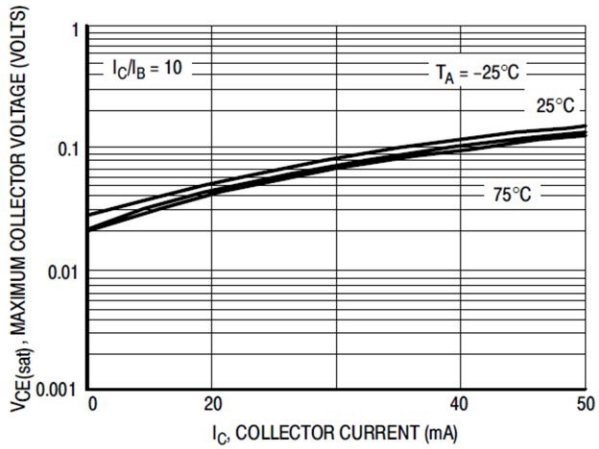


Figure 3. DC Current Gain

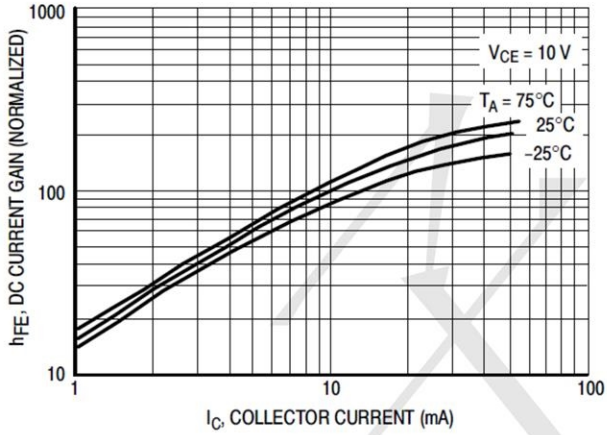


Figure 4. Output Capacitance

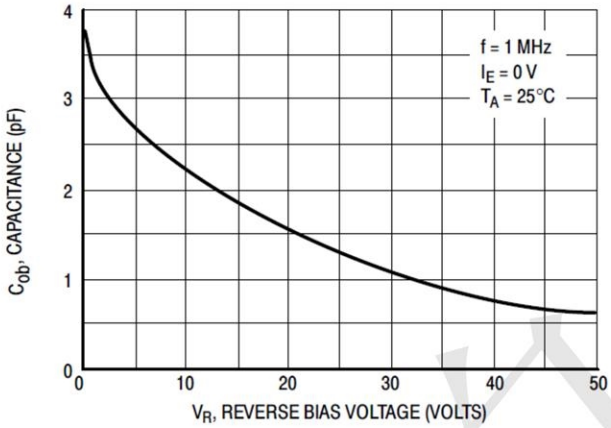


Figure 5. Output Current vs. Input Voltage

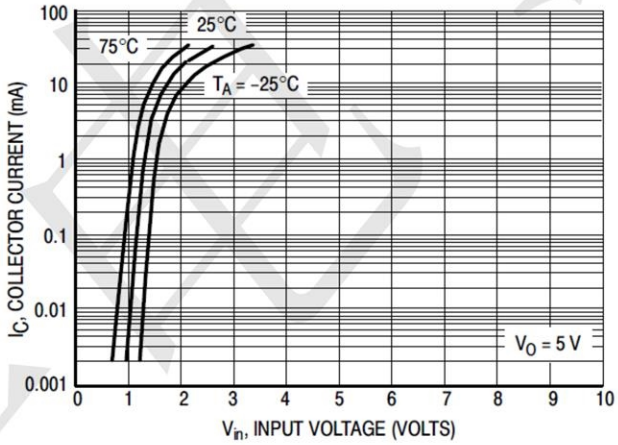
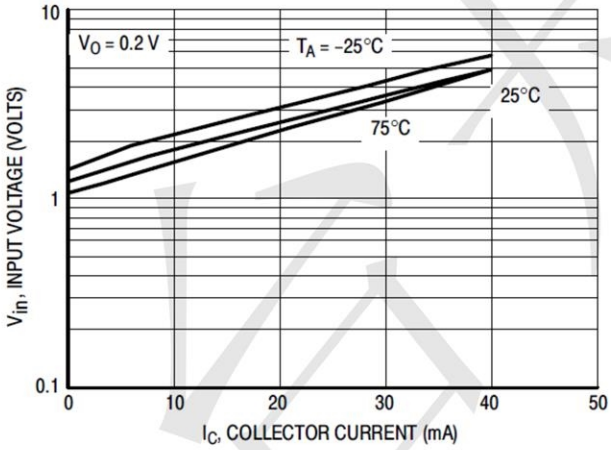


Figure 6. Input Voltage vs. Output Current



DTC124EM

Figure 7. $V_{CE(sat)}$ vs. I_C

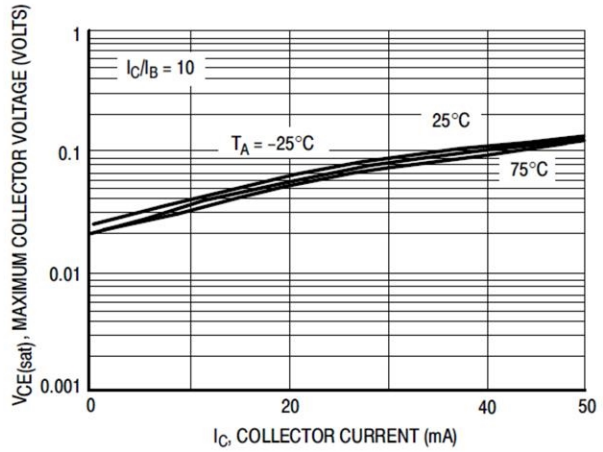


Figure 8. DC Current Gain

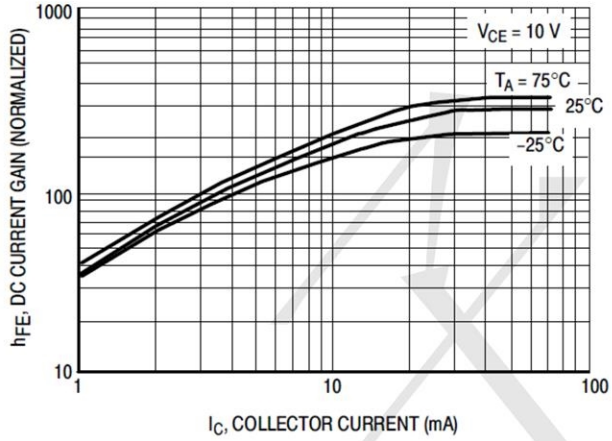


Figure 9. Output Capacitance

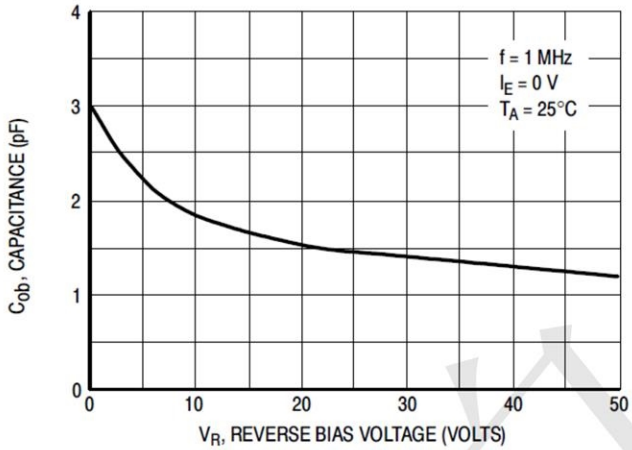


Figure 10. Output Current vs. Input Voltage

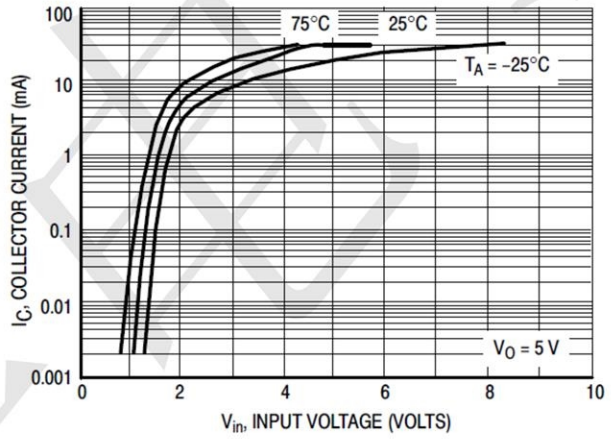
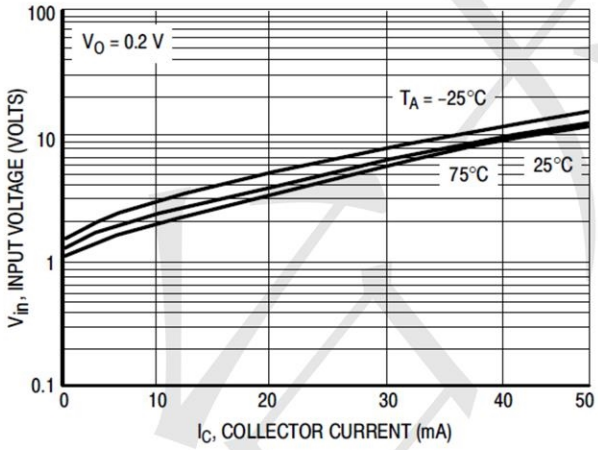


Figure 11. Input Voltage vs. Output Current



DTC144EM

Figure 12. $V_{CE(sat)}$ vs. I_C

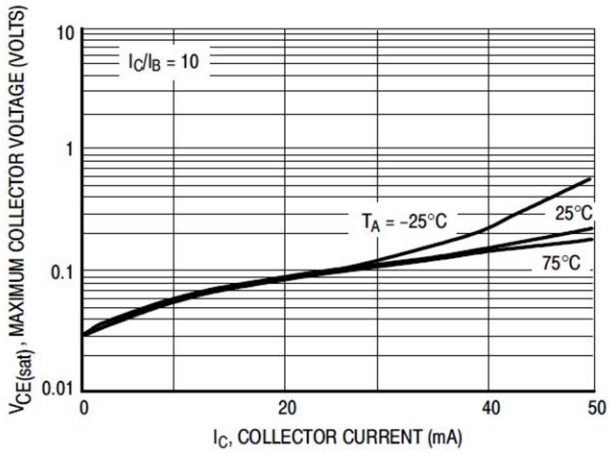


Figure 13. DC Current Gain

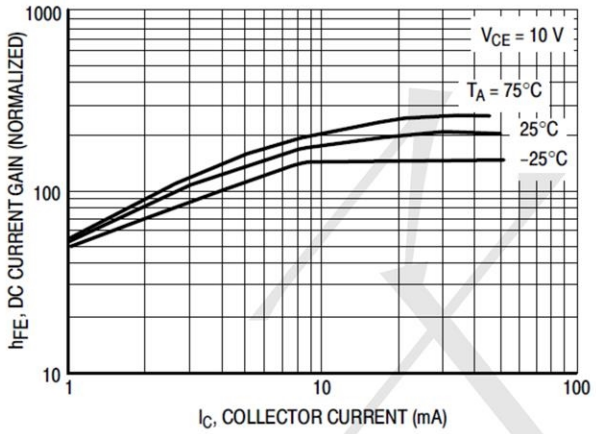


Figure 14. Output Capacitance

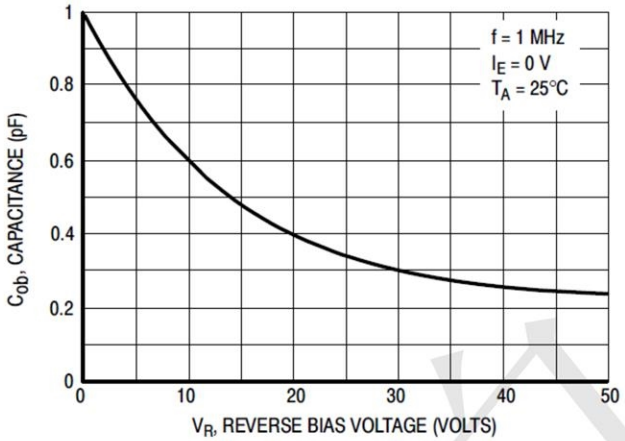


Figure 15. Output Current vs. Input Voltage

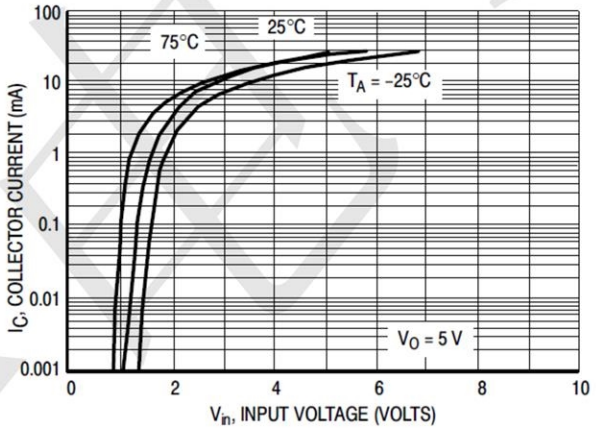
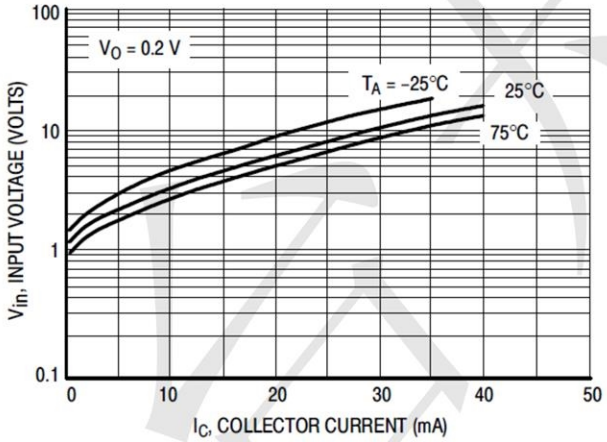


Figure 16. Input Voltage vs. Output Current



DTC114YM

Figure 17. $V_{CE(sat)}$ vs. I_C

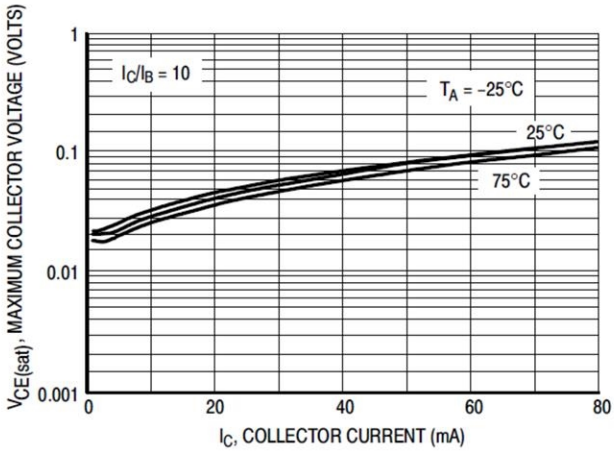


Figure 18. DC Current Gain

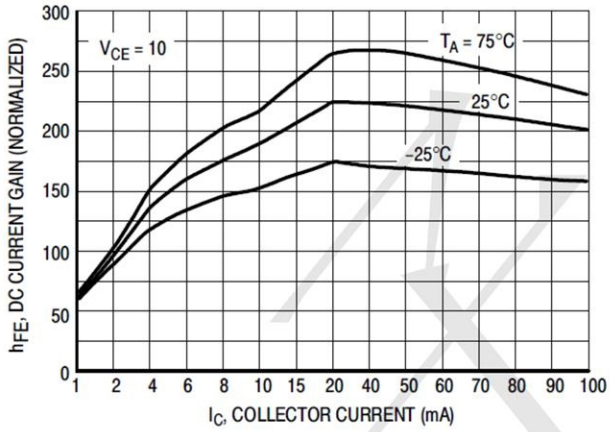


Figure 19. Output Capacitance

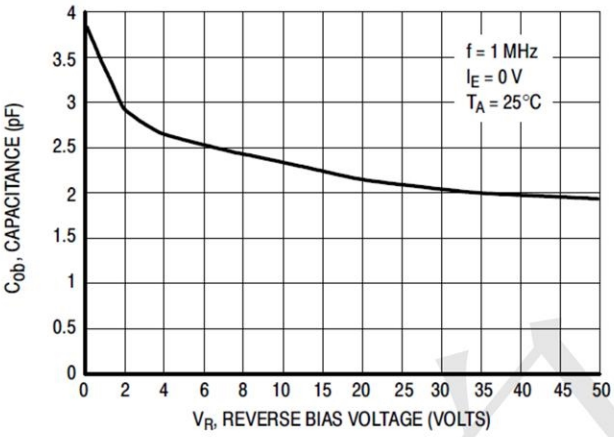


Figure 20. Output Current vs. Input Voltage

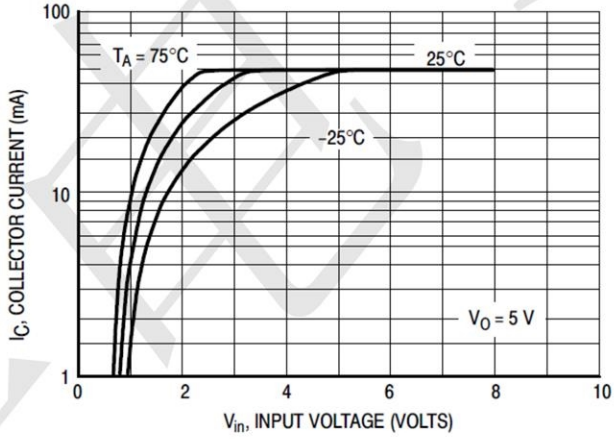
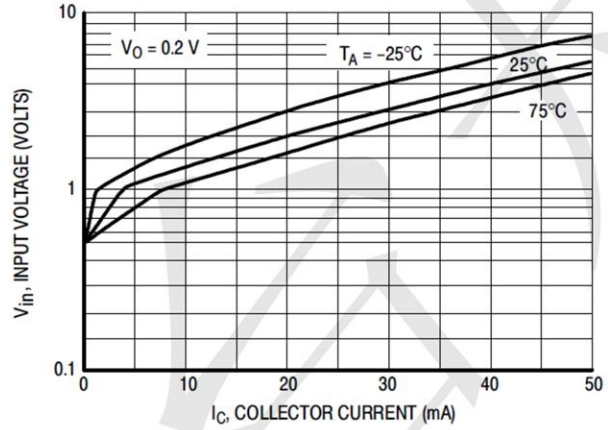


Figure 21. Input Voltage vs. Output Current



DTC143ZM

Figure 22. $V_{CE(sat)}$ versus I_C

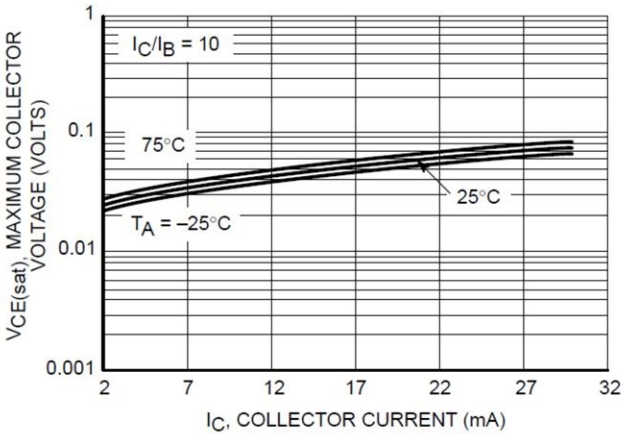


Figure 23. DC Current Gain

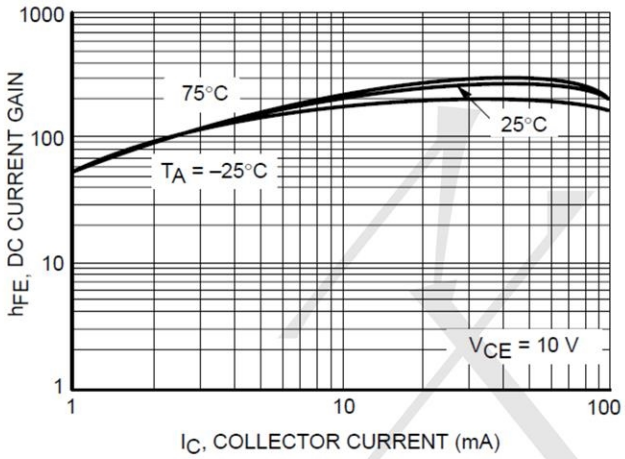


Figure 24. Output Capacitance

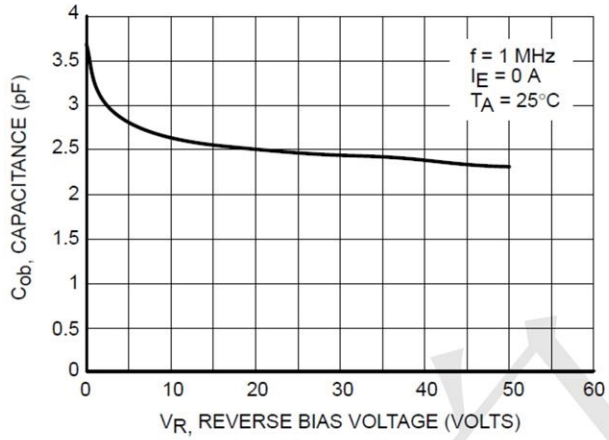


Figure 25. Output Current vs. Input Voltage

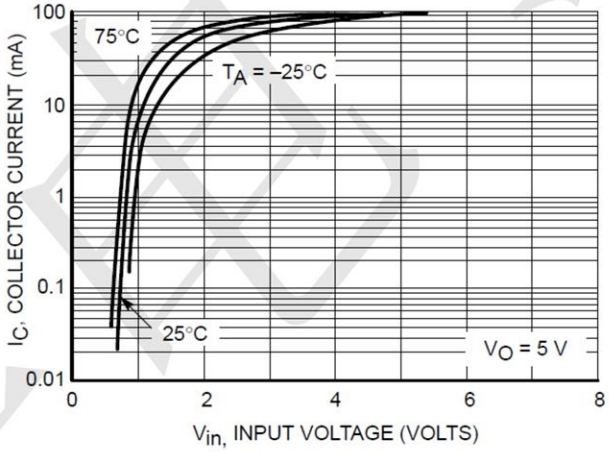
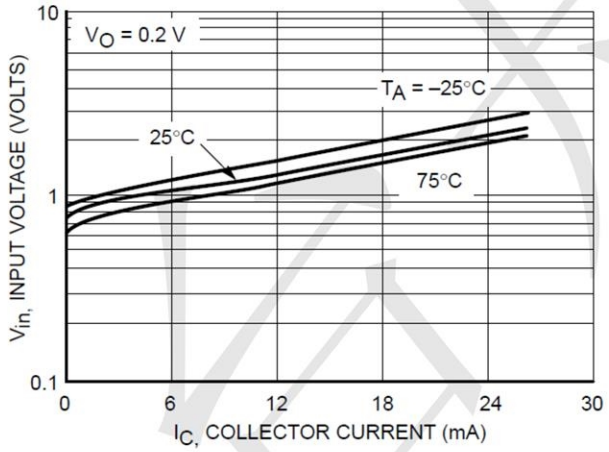


Figure 26. Input Voltage vs. Output Current



TYPICAL APPLICATIONS FOR NPN BRTs

Figure 27. Level Shifter: Connects 12 or 24 Volt Circuits to Logic

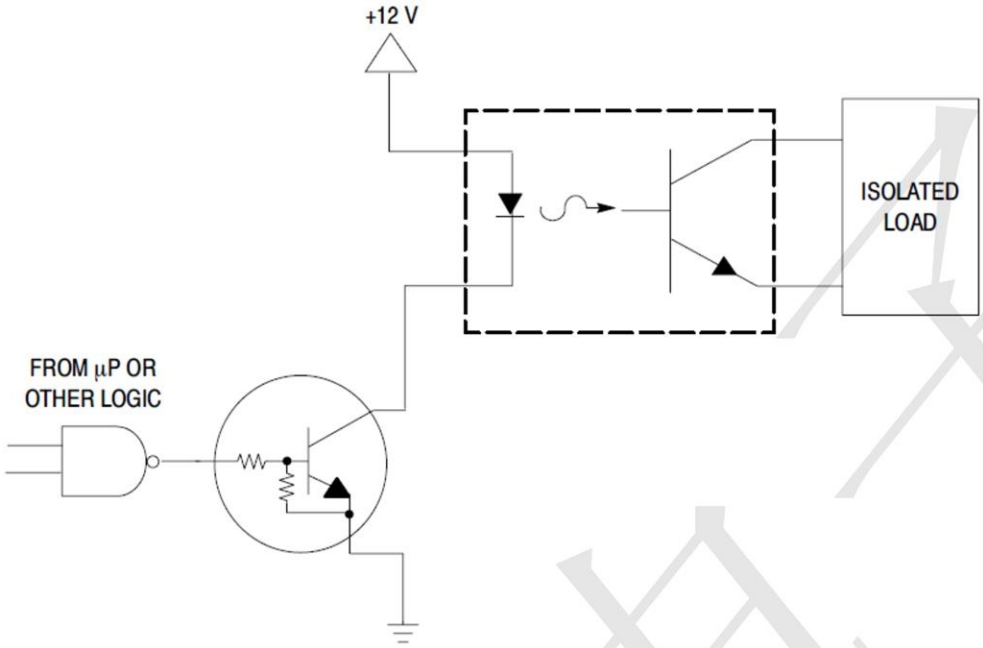


Figure 28. Open Collector Inverter:
Inverts the Input Signal

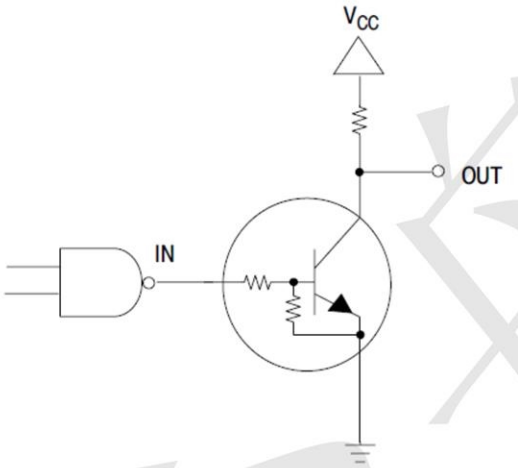
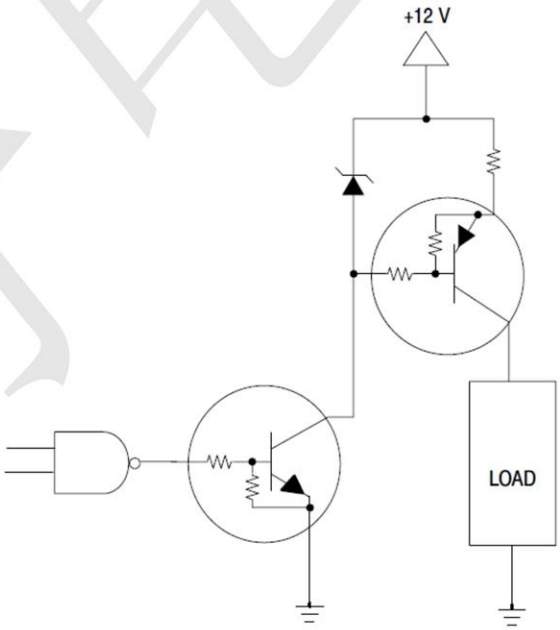
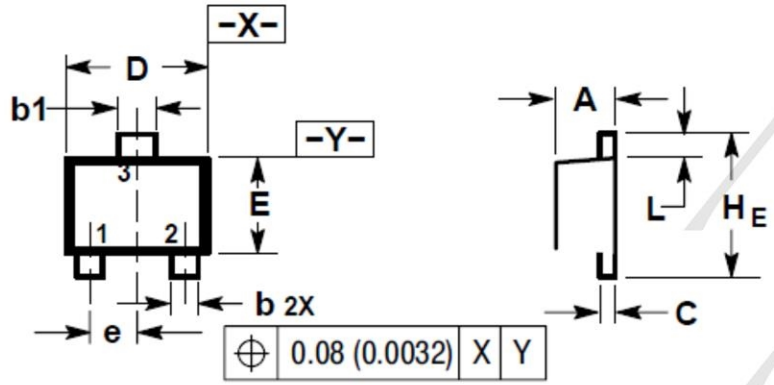


Figure 29. Inexpensive, Unregulated Current Source

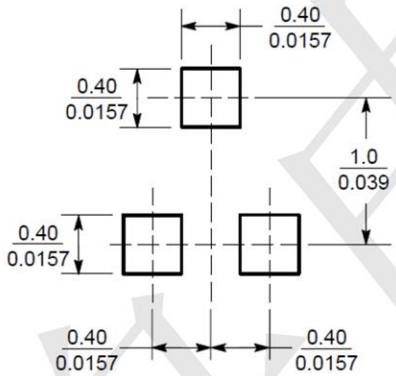


PACKAGE INFORMATION

Dimension in SOT-723 (Unit: mm)



SOLDERING FOOTPRINT



(mm / inches)

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.45	0.55	0.018	0.022
b	0.15	0.27	0.0059	0.0106
b1	0.25	0.35	0.010	0.014
C	0.07	0.17	0.0028	0.0067
D	1.15	1.25	0.045	0.049
E	0.75	0.85	0.03	0.034
e	0.40 BSC		0.016 BSC	
H_E	1.15	1.25	0.045	0.049
L	0.15	0.25	0.0059	0.0098

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RN1607(TE85L,F) DRC9A14E0L DTA124GKAT146 DTA144WETL DTA144WKAT146 DTC113EET1G DTC115TETL DTC115TKAT146 DTC124TETL DTC144VUAT106 MUN5241T1G BCR158WH6327XTSA1 NSBA114TDP6T5G NSBA123EF3T5G NSBA143TF3T5G NSBA144TF3T5G NSBC113EF3T5G NSBC124XF3T5G SMUN5330DW1T1G SSVMUN5312DW1T2G RN1303(TE85L,F) RN1306(TE85L,F) RN4605(TE85L,F) TTEPROTOTYPE79 EMH15T2R SMUN2214T3G SMUN5335DW1T1G NSBC143ZPDP6T5G NSVDTA143ZET1G NSVMUN5113DW1T3G SMUN2214T1G FMA7AT148 DTC114EUA-TP SMUN5237DW1T1G SMUN5213DW1T1G SMUN5114DW1T1G SMUN2111T1G DTC124ECA-TP DTC123TM3T5G DTA114ECA-TP DTA113EM3T5G DTC113EM3T5G NSVMUN5135DW1T1G NSVMUN2237T1G NSVDTC143ZM3T5G SMUN5335DW1T2G SMUN5216DW1T1G NSVMUN5316DW1T1G NSVMUN5215DW1T1G NSVMUN5213DW1T3G